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Fairchild Semiconductor FDC608PZ

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Distributor of Fairchild Semiconductor: Excellent Integrated System Limited Datasheet of FDC608PZ - MOSFET P-CH 20V 5.8A SSOT-6 Contact us: sales@integrated-circuit.com Website: www.integrated-circuit.com

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FDC608PZ

P-Channel 2.5V Specified PowerTrench[®] MOSFET

General Description

This P-Channel 2.5V specified MOSFET is produced using Fairchild Semiconductor's advanced PowerTrench process that has been especially tailored to minimize the on-state resistance and yet maintain low gate charge for superior switching performance.

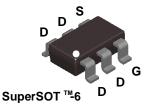
These devices are well suited for battery power applications: load switching and power management, battery power circuits, and DC/DC conversions.

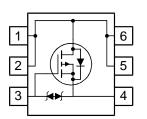


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Features

- -5.8 A, -20 V. $R_{DS(ON)} = 30 \text{ m}\Omega @ V_{GS} = -4.5 \text{ V}$ $R_{DS(ON)} = 43 \text{ m}\Omega @ V_{GS} = -2.5 \text{ V}$
- Low Gate Charge
- High performance trench technology for extremely low R_{DS(ON)}
- SuperSOT [™] –6 package: small footprint (72% smaller than standard SO–8) low profile (1mm thick).





Absolute Maximum Ratings T_A=25°C unless otherwise noted

Symbol		Parameter	•	Ratings	Units
V _{DSS}	Drain-Source	urce Voltage		-20	V
V _{GSS}	Gate-Source	Gate-Source Voltage		±12	V
I _D	Drain Currer	nt – Continuous	(Note 1a)	-5.8	A
		– Pulsed		-20	
PD	Maximum Po	ower Dissipation	(Note 1a)	1.6	W
			(Note 1b)	0.8	
тт	Operating ar	nd Storage Junction T	emperature Range	-55 to +150	°C
TJ, TSTG Therma	al Charact	Ū			
Therma R _{eja}	Thermal Res	Ū	Ambient (Note 1a)	78 30	
Therma R _{θJA} R _{θJC}	Al Charact Thermal Res Thermal Res	sistance, Junction-to-/	Ambient (Note 1a) Case (Note 1)	78	°C/W °C/W
Therma R _{0JA} R _{0JC} Packag	Al Charact Thermal Res Thermal Res	sistance, Junction-to-/	Ambient (Note 1a)	78	

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FDC608PZ Rev B (W)



Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
•	acteristics			,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,		
BV _{DSS}	Drain–Source Breakdown Voltage	V _{GS} = 0 V, I _D = -250 μA	-20	İ	İ	V
	Breakdown Voltage Temperature	$I_D = -250 \ \mu$ A,Referenced to 25°C		-10		mV/°C
ΔT_J	Coefficient					
DSS	Zero Gate Voltage Drain Current	$V_{DS} = -16 \text{ V}, V_{GS} = 0 \text{ V}$			-1	μA
GSS	Gate-Body Leakage	$V_{GS}=\pm 12~V, \qquad V_{DS}=0~V$			±10	μΑ
On Char	acteristics (Note 2)				•	
V _{GS(th)}	Gate Threshold Voltage	$V_{DS} = V_{GS}, I_D = -250 \ \mu A$	-0.4	-1.0	-1.5	V
ΔV _{GS(th)} ΔT _{.1}	Gate Threshold Voltage Temperature Coefficient	$I_D = -250 \ \mu$ A,Referenced to 25°C		3		mV/°C
R _{DS(on)}	Static Drain-Source	$V_{GS} = -4.5V, \qquad I_D = -5.8 \text{ A}$		26	30	mΩ
	On–Resistance	$V_{GS} = -2.5V, I_D = -5.0 A$		38	43	
1	On–State Drain Current	$V_{GS} = -4.5V, I_D = -5.8A, T_J = 125^{\circ}C$	-20	35		٨
D(on)	Forward Transconductance	$V_{GS} = -4.5 V, V_{DS} = -5 V$ $V_{DS} = -10 V, I_{D} = -5.8 A$	-20	22		A S
9 _{FS}		$V_{DS} = -10 V$, $I_D = -5.8 A$		22		3
	Characteristics		1		1	
Ciss	Input Capacitance	$V_{DS} = -10 \text{ V}, \qquad V_{GS} = 0 \text{ V},$		1330		pF
C _{oss}	Output Capacitance	f = 1.0 MHz		270		pF
C _{rss}	Reverse Transfer Capacitance			230		pF
R _G	Gate Resistance	V_{GS} = 15 mV, f = 1.0 MHz		12		Ω
Switchin	g Characteristics (Note 2)					
d(on)	Turn–On Delay Time	$V_{DD} = -10 V$, $I_D = -1 A$,		13	24	ns
tr	Turn–On Rise Time	$V_{GS} = -4.5 \text{ V}, \qquad R_{GEN} = 6 \ \Omega$		8	16	ns
t _{d(off)}	Turn–Off Delay Time			91	145	ns
t _f	Turn–Off Fall Time			60	96	ns
Qg	Total Gate Charge	$V_{DS} = -10 \text{ V}, I_D = -5.8 \text{ A},$		17	23	nC
Q _{gs}	Gate–Source Charge	$V_{GS} = -4.5 V$		3		nC
Q _{gd}	Gate–Drain Charge	7		6		nC
	ource Diode Characteristics	and Maximum Ratings				
ls	Maximum Continuous Drain–Source				-1.3	A
V _{SD}	Drain–Source Diode Forward Voltage	$V_{GS} = 0 V$, $I_S = -1.3 A$ (Note 2)		-0.7	-1.2	V
t _{rr}	Diode Reverse Recovery Time	$I_F = -5.8 \text{ A}, d_{iF}/d_t = 100 \text{A}/\mu \text{s}$		40	60	ns
Q _{rr}	Diode Reverse Recovery Charge	$I_F = -5.8 \text{ A}, d_{iF}/d_t = 100 \text{A}/\mu \text{s}$		15	23	nC

1. R_{BJA} is the sum of the junction-to-case and case-to-ambient resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. $R_{\theta JC}$ is guaranteed by design while $R_{\theta CA}$ is determined by the user's board design.

a. $~78^\circ\text{C/W}$ when mounted on a 1in^2 pad of 2oz copper on FR-4 board.

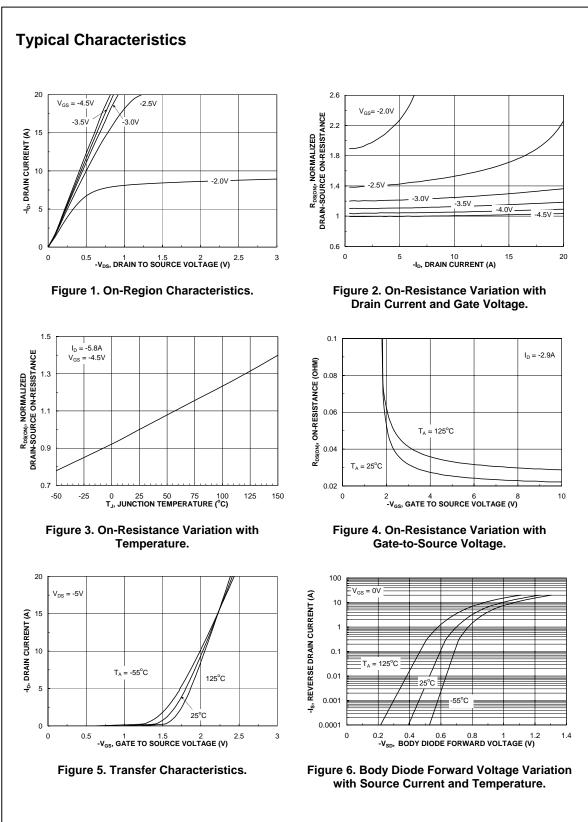
b. 156°C/W when mounted on a minimum pad.

2. Pulse Test: Pulse Width $\leq 300~\mu\text{s},$ Duty Cycle $\leq 2.0\%$

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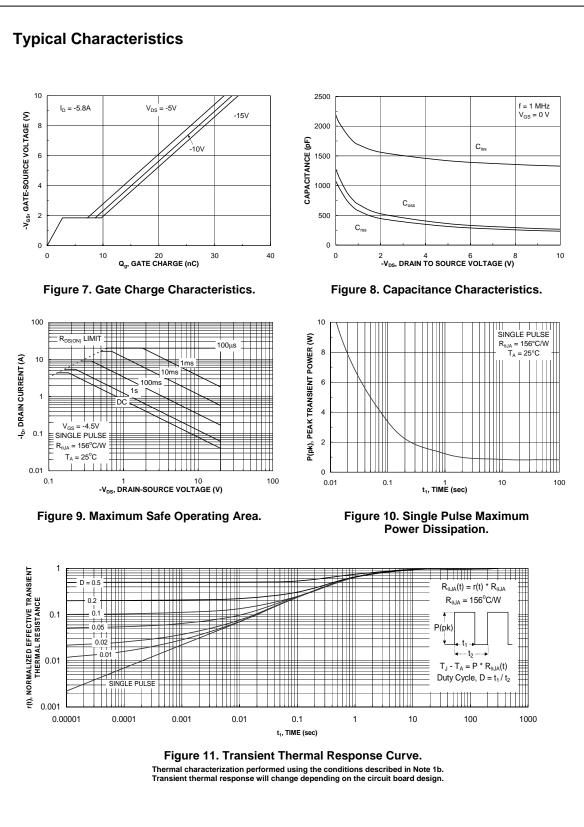
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2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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